

WHAT IS CLAIMED IS:

1. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers accommodated in the load lock chamber out of the load lock chamber in a vacuum state and loading etched wafers in the load lock chamber, a rotary robot for rotatively transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade, and a heater stage for etching the wafers transferred by the rotary robot using a plasma generator,

wherein the load lock chamber is placed at each of both sides of the reaction chamber adjacent to the stand-by conveying robot so that the wafers transferred by the stand-by conveying robot can be continuously loaded into or taken out of the load lock chamber even in the process of etching other wafers.

2. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers accommodated in the load lock chamber out of the load lock chamber in a vacuum state and loading etched wafers in the load lock chamber, a rotary robot for rotatively transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade,

and a heater stage for etching the wafers transferred by the rotary robot using a plasma generator,

wherein the stand-by conveying robot is placed between the cassette station and the load lock chamber and it has a rotatable arm for taking the wafers out of the cassette station and loading them in the load lock chamber and a plurality of blades, formed at the front end of the arm, for carrying a plurality of wafers.

3. The semiconductor manufacturing apparatus as claimed in claim 2, wherein the blades of the arm make the wafers put on the arm according to vacuum absorption.

4. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber having a wafer holder in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers accommodated in the load lock chamber out of the load lock chamber in a vacuum state and loading etched wafers in the load lock chamber, a rotary robot for rotatively transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade, and a heater stage for etching the wafers transferred by the rotary robot using a plasma generator,

wherein the wafer holder can be moved upward and downward to permit the wafers horizontally transferred by the stand-by conveying robot or shuttle blade to be sequentially loaded into or taken out of the wafer holder, and it can be rotated to axially rotate the wafers loaded or taken toward the reaction chamber or stand-by conveying robot to allow

the stand-by conveying robot or shuttle blade to be able to easily draw the wafers therefrom according to horizontal movement.

5. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers accommodated in the load lock chamber out of the load lock chamber in a vacuum state and loading etched wafers in the load lock chamber, a rotary robot for rotatively transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade, and a heater stage for etching the wafers transferred by the rotary robot using a plasma generator,

wherein the shuttle blade is operated by an air cylinder to transfer the wafers loaded in the wafer holder of the load lock chamber to the reaction chamber and transfer etched wafers back to the load lock chamber.

6. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers accommodated in the load lock chamber out of the load lock chamber in a vacuum state and loading etched wafers in the load lock chamber, a rotary robot for rotatively transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade,

and a heater stage for etching the wafers transferred by the rotary robot using a plasma generator,

wherein a pre-heating part is placed above the shuttle blade, for pre-heating the wafers transferred into the reaction chamber from the load lock chamber before they are moved to the heater stage in order to improve etch rate.

7. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers accommodated in the load lock chamber out of the load lock chamber in a vacuum state and loading etched wafers in the load lock chamber, a rotary robot for rotatively transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade, and a heater stage for etching the wafers transferred by the rotary robot using a plasma generator,

wherein the plasma generator is set corresponding to each heater stage to allow different gases or the same gas to be introduced into the reaction chamber for plasma process with a controller.

8. A semiconductor manufacturing apparatus comprising: a cassette station in which wafers are loaded; a stand-by conveying robot for taking the wafers out of the cassette station; a load lock chamber in which the wafers taken by the stand-by conveying robot are accommodated; and a reaction chamber placed in contact with the load lock chamber, the reaction chamber having a shuttle blade for drawing the wafers

accommodated in the load lock chamber out of the load lock chamber in a vacuum state
and loading etched wafers in the load lock chamber, a rotary robot for rotatively
transferring the wafers taken out of the load lock chamber to be placed on the shuttle blade,
and a heater stage for etching the wafers transferred by the rotary robot using a plasma
5 generator,

wherein the reaction chamber has multiple heater stages, each heater stage being
capable of controlling temperature independently.

9. The semiconductor manufacturing apparatus as claimed in claim 1,
10 wherein an auxiliary plasma generator is set under a predetermined part of the reaction
chamber in order to remove remnants attached onto the backside of a wafer before the
wafer is placed on the shuttle blade to be transferred.

10. The semiconductor manufacturing apparatus as claimed in claim 2,
15 wherein an auxiliary plasma generator is set under a predetermined part of the reaction
chamber in order to remove remnants attached onto the backside of a wafer before the
wafer is placed on the shuttle blade to be transferred.

11. The semiconductor manufacturing apparatus as claimed in claim 3,
20 wherein an auxiliary plasma generator is set under a predetermined part of the reaction
chamber in order to remove remnants attached onto the backside of a wafer before the
wafer is placed on the shuttle blade to be transferred.

12. The semiconductor manufacturing apparatus as claimed in claim 4,
25 wherein an auxiliary plasma generator is set under a predetermined part of the reaction

chamber in order to remove remnants attached onto the backside of a wafer before the wafer is placed on the shuttle blade to be transferred.

13. The semiconductor manufacturing apparatus as claimed in claim 5,
5 wherein an auxiliary plasma generator is set under a predetermined part of the reaction chamber in order to remove remnants attached onto the backside of a wafer before the wafer is placed on the shuttle blade to be transferred.

14. The semiconductor manufacturing apparatus as claimed in claim 6,
10 wherein an auxiliary plasma generator is set under a predetermined part of the reaction chamber in order to remove remnants attached onto the backside of a wafer before the wafer is placed on the shuttle blade to be transferred.

15. The semiconductor manufacturing apparatus as claimed in claim 7,
15 wherein an auxiliary plasma generator is set under a predetermined part of the reaction chamber in order to remove remnants attached onto the backside of a wafer before the wafer is placed on the shuttle blade to be transferred.

16. The semiconductor manufacturing apparatus as claimed in claim 8,
20 wherein an auxiliary plasma generator is set under a predetermined part of the reaction chamber in order to remove remnants attached onto the backside of a wafer before the wafer is placed on the shuttle blade to be transferred.